

## LOW NOISE STEREO PREAMPLIFIER

PRODUCT PREVIEW

- DUAL CHANNEL PROCESSOR FOR PLAYBACK APPLICATIONS.
- LOW NOISE HEAD PREAMPLIFIER GROUND COMPATIBLE
- MUTE, AUTOREVERSE METAL/NORMAL FUNCTIONS
- INTERNAL SWITCHES FOR EQUALIZATION
- LOW SUPPLY CURRENT
- MIXED BIPOLAR/CMOS TECHNOLOGY

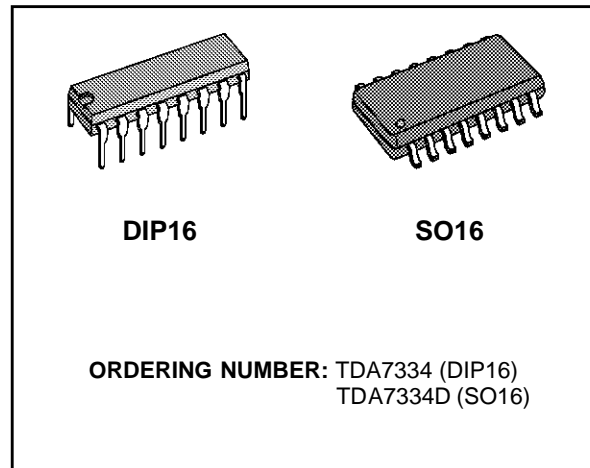
### DESCRIPTION

The TDA7334 is a monolithic BiCMos IC designed for use in stereo cassette player systems.

The dual preamplifier contains mute, autoreverse, metal/normal facilities for amplification of low level signal in applications requiring very low noise performance.

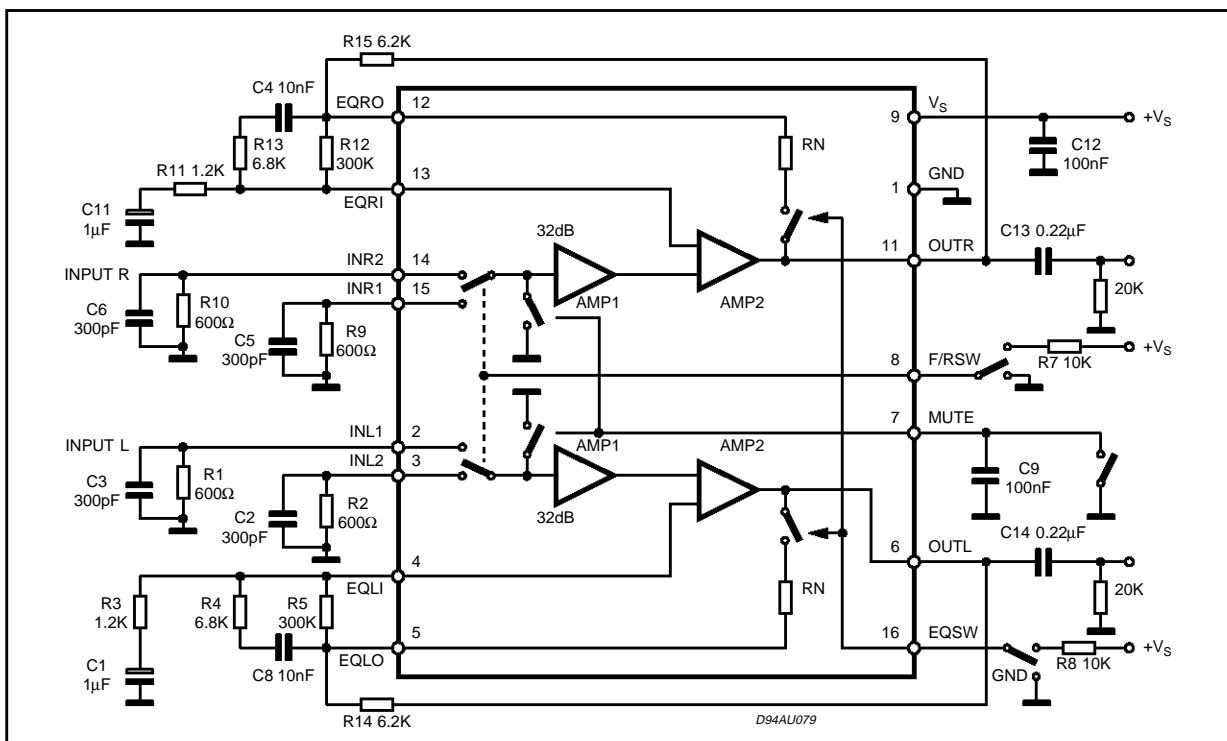
Each channel consists of two cascaded operational amplifiers.

The first one, AMP1, has a fixed gain of 32dB,



low noise forward/reverse switchable input, and allows magnetic heads connection directly to ground. The second one, AMP2, is a standard operational amplifier whose equalizing external components fix the frequency response.

### TEST CIRCUIT

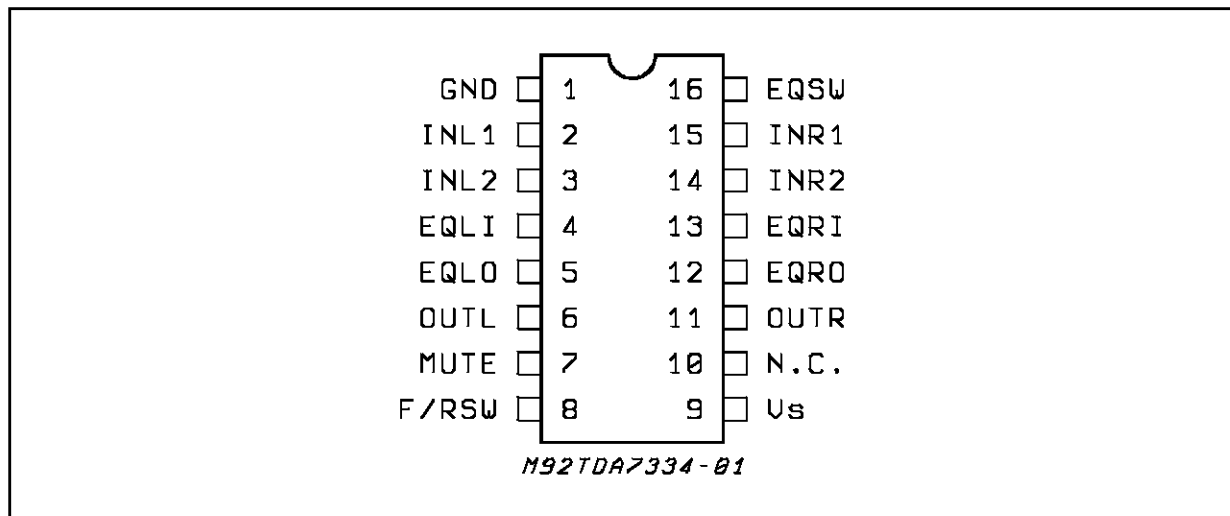


## TDA7334

### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>s</sub>	Supply Voltage	12	V
P <sub>tot</sub>	Total Power Dissipation	1	W
T <sub>op</sub>	Operating Temperature Range	-40 to 85	°C
T <sub>stg</sub>	Storage Temperature Range	-40 to 150	°C

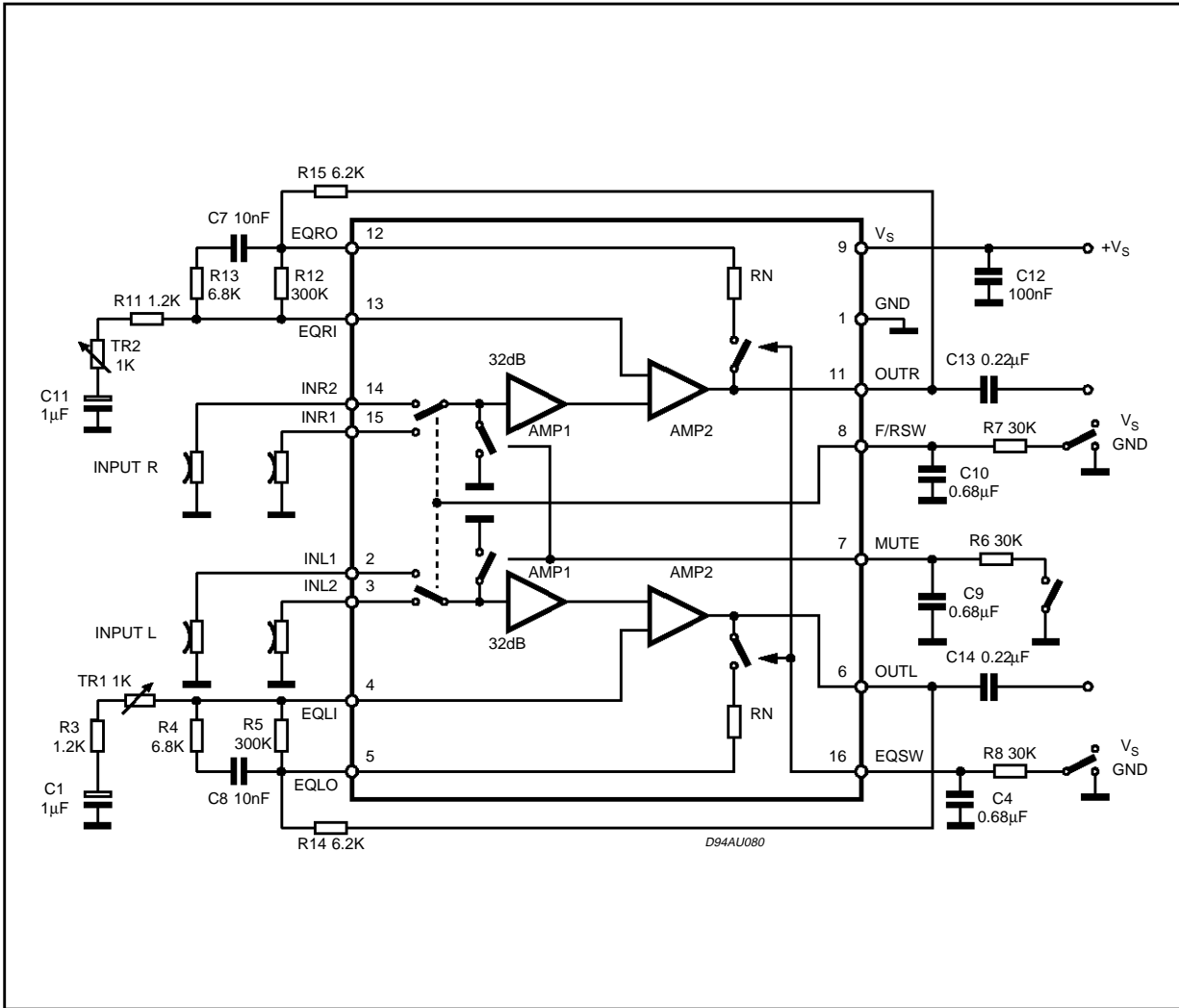
### PIN CONNECTION (Top view)



### THERMAL DATA

		DIP 16	SO16	
R <sub>th j-pins</sub>	Thermal resistance junction-pins	100	200	°C/W

Figure 1: Application Circuit



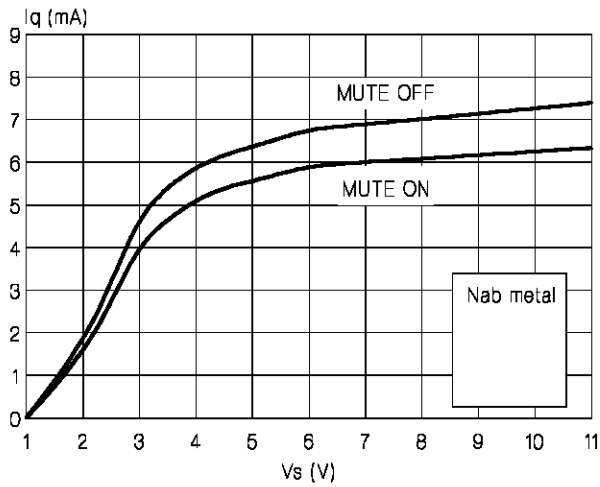
PIN	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
DC (V)	GND	0	0	3.6	3.6	3.6			8.0	N.C.	3.6	3.6	3.6	0	0	

## TDA7334

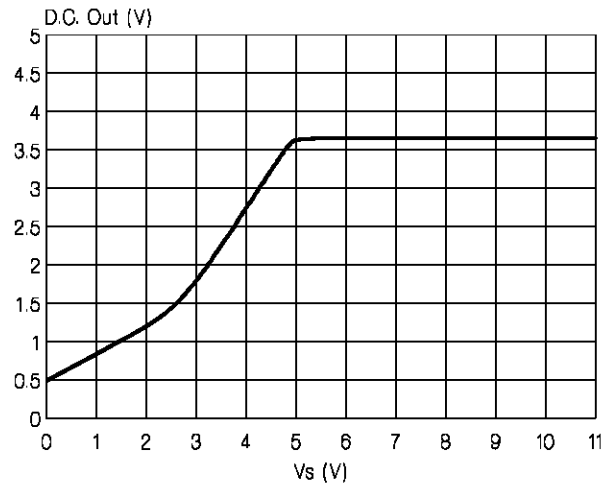
**ELECTRICAL CHARACTERISTICS** ( $V_s = 8V$ ;  $R_{IN} = 600\Omega$ ;  $f = 1KHz$ ;  $T_{amb} = 25^\circ C$ ; unless otherwise specified (see figure 2))

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_s$	Supply Voltage		6	8	11	V
$I_s$	Supply Current			7.5		mA
SVR	Ripple Rejection	Input referred (ripple = 1V)		105		dB
MUTE <sub>th</sub>	Mute (Pin 7)	OFF ON	0 3.2		0.8 $V_s$	V V
MUTE <sub>A</sub>	Mute Attenuation			80		dB
$R_I$	Input Resistance		100			K $\Omega$
$V_{out DC}$	Output Voltage DC			3.6		V
$I_I$	Input Bias Current				10	$\mu A$
$G_{VO}$	Open Loop Gain	$f = 400Hz$		110		dB
$G_V$	Closed Loop Gain	NAB short		32		dB
$\Delta G_V$	Closed Loop Gain Match	NAB short	-1		1	dB
$V_{OM}$	Signal Handling	THD = 1%, $V_{CC} = 7.6V$		2.0		V <sub>rms</sub>
$R_N$	Resistance Normal Position				700	$\Omega$
$S_R$	Slew Rate	NAB Short		1		V/ $\mu s$
$e_N$	Total Input Noise	$R_{IN} = 600\Omega$ ; unweighted		0.8		$\mu V$
		$R_{IN} = 600\Omega$ ; A weighted		0.5		$\mu V$
		$R_{IN} = 0$ ; unweighted		0.45		$\mu V$
$R_o$	Output Resistance				1	K $\Omega$
$L_{Omin}$	Minimum Resistance Load			1		K $\Omega$
F/R <sub>l</sub>	Rev. Low Level (pin 8)	IN2 = ON; IN1 = OFF	0		0.8	V
F/R <sub>h</sub>	Forward High Level (pin 8)	IN2 = OFF; IN1 = ON	3.2		$V_s$	V
EQ <sub>l</sub>	Normal Low Level (pin 16)		0		0.8	V
EQ <sub>h</sub>	Metal High Level (pin 16)		3.2		$V_s$	V
THD	Total Harmonic Distortion	$V_o = 1V$ ; $f = 1KHz$ metal		0.02		%
		$V_o = 1V$ ; $f = 1KHz$ normal		0.02		%
		$V_o = 1V$ ; $f = 10KHz$ metal		0.05		%
		$V_o = 1V$ ; $f = 10KHz$ normal		0.04		%
SVR <sub>1</sub>	Ripple Rejection	NAB short		75		dB
$C_s$	Channel Separation			60		dB
$C_{CT}$	Channel Cross talk			80		dB
S/N	Signal to Noise	$V_o = 388mV$ ; metal		63		dB

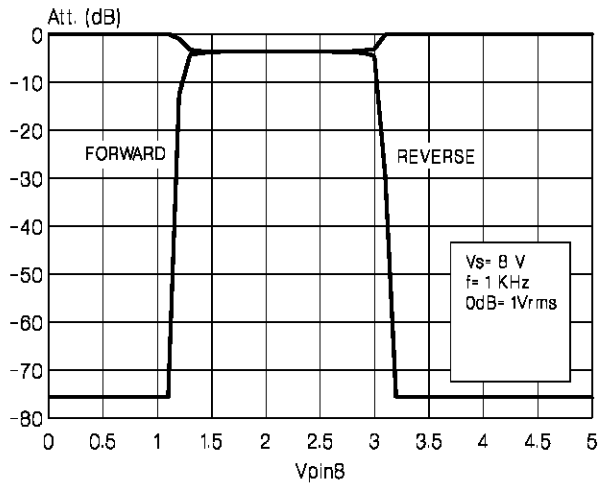
**Figure 1:** Quiescent Current vs. Supply



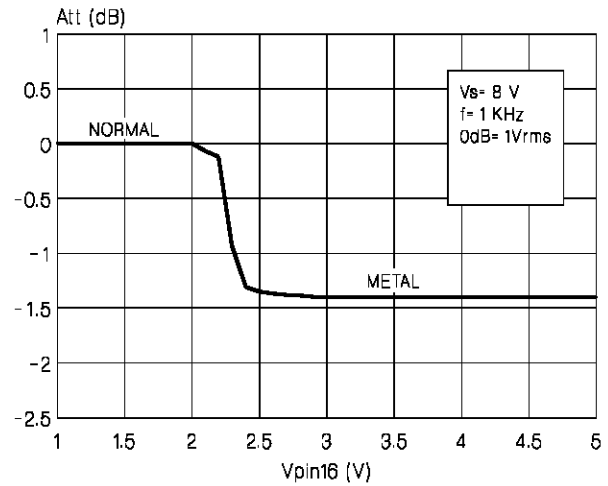
**Figure 2:** D.C. Output vs. Supply Voltage



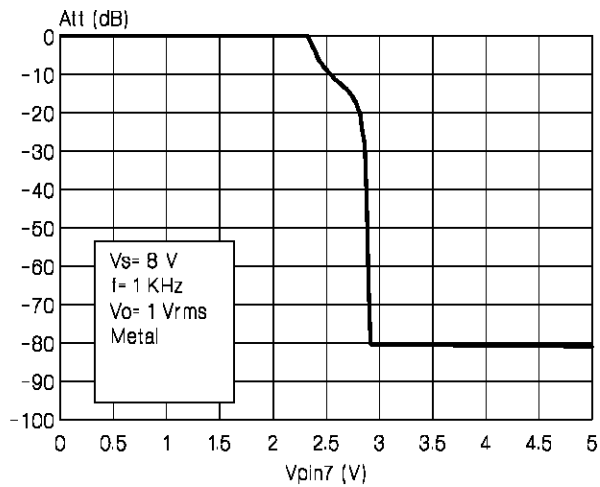
**Figure 3:** Forward/Reverse Threshold



**Figure 4:** Metal/Normal Threshold



**Figure 5:** Mute Threshold



**Figure 6:** Mute Attenuation vs. Frequency

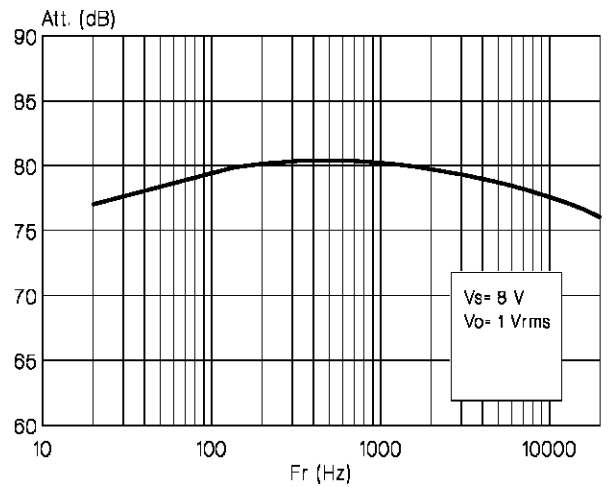


Figure 7: Mute Attenuation vs. Output Level

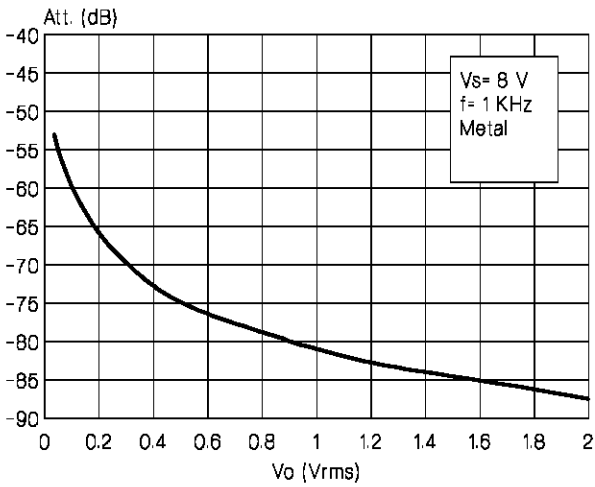


Figure 9: THD + N vs. Frequency

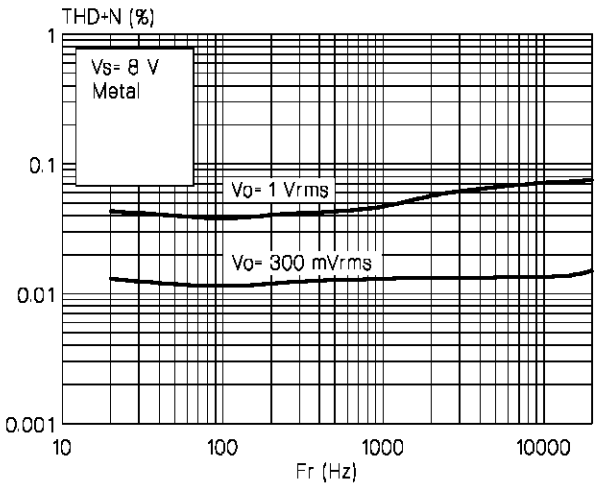


Figure 11: Load Characteristic

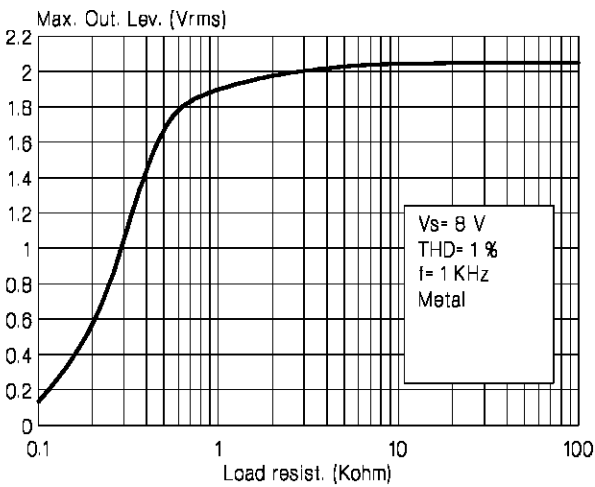


Figure 8: THD vs. Frequency

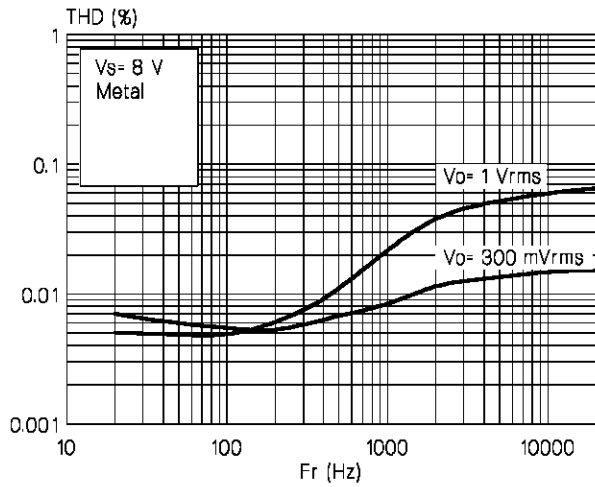


Figure 10: THD vs. Supply Voltage

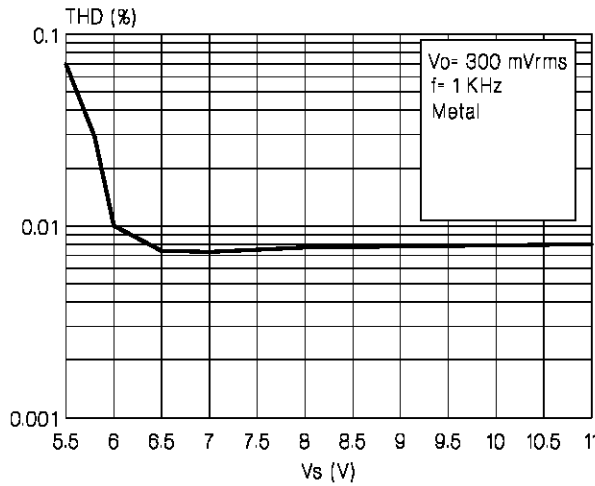


Figure 12: Signal Handling vs. Supply Voltage

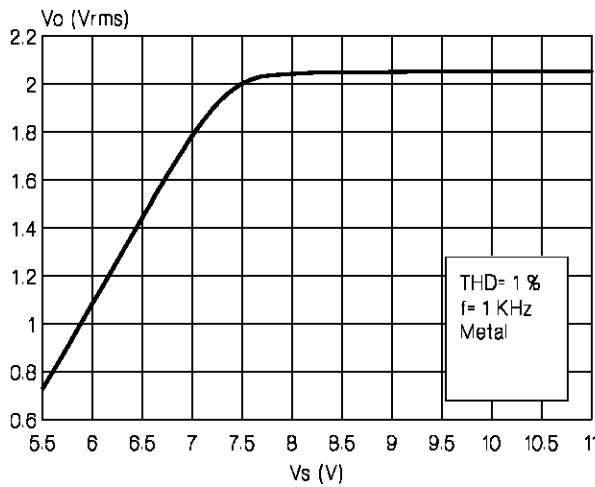


Figure 13: Total Input Noise vs. Input Resistance

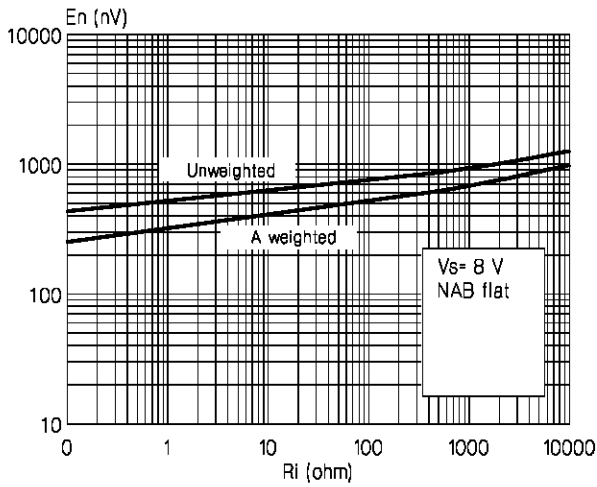


Figure 14: Cross Channel vs. Frequency

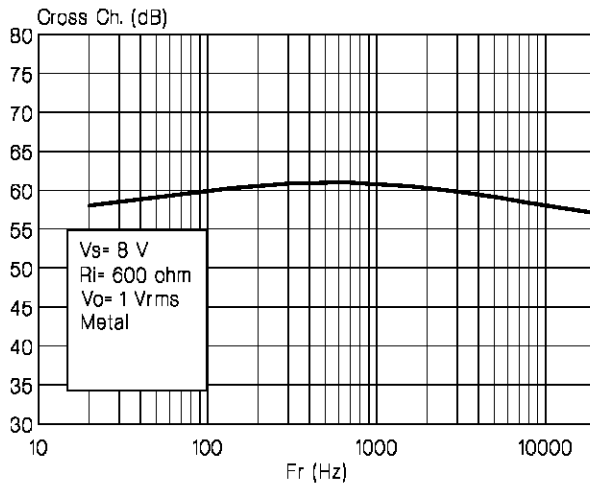


Figure 15: Cross Talk vs. Frequency

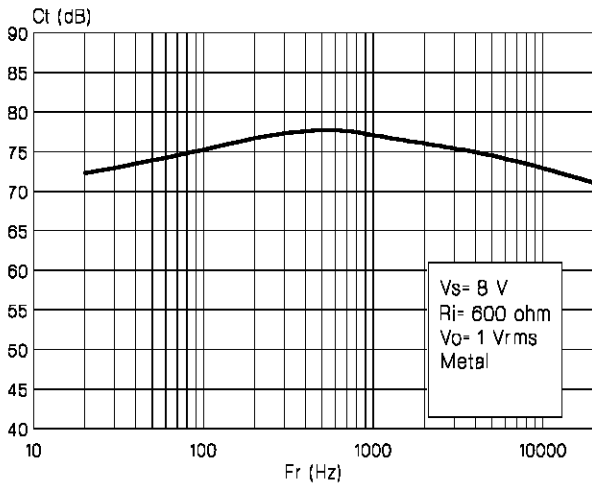


Figure 16: SVR vs. Frequency

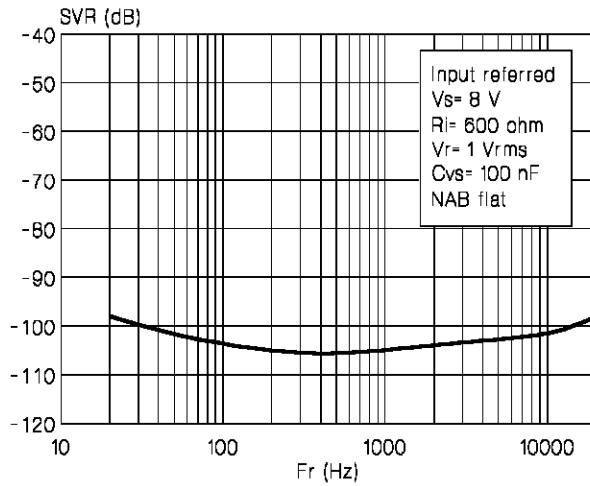


Figure 17: SVR vs. Frequency

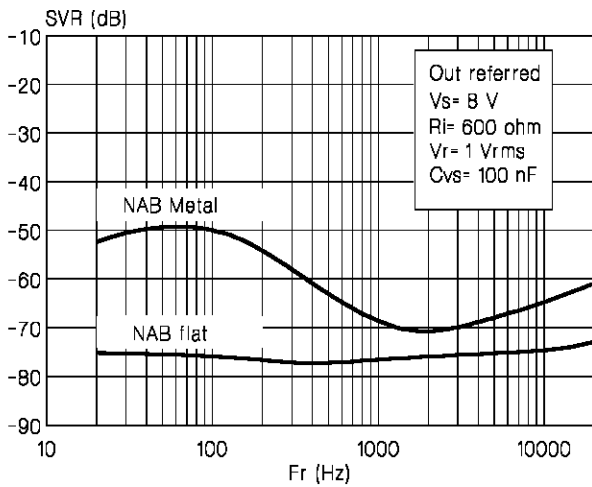


Figure 18: Power Bandwidth

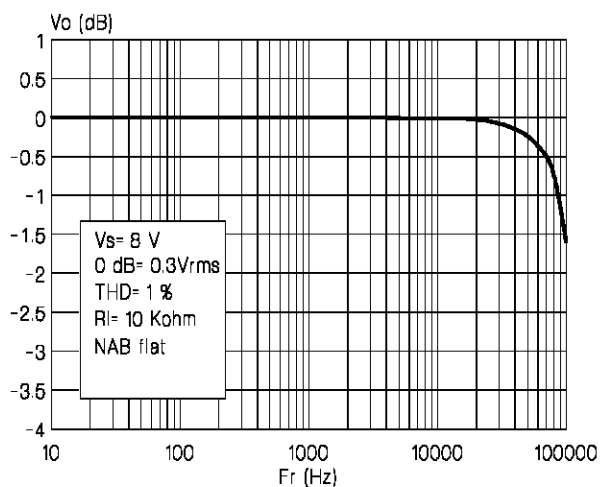


Figure 19: Voltage Gain vs. Input Voltage

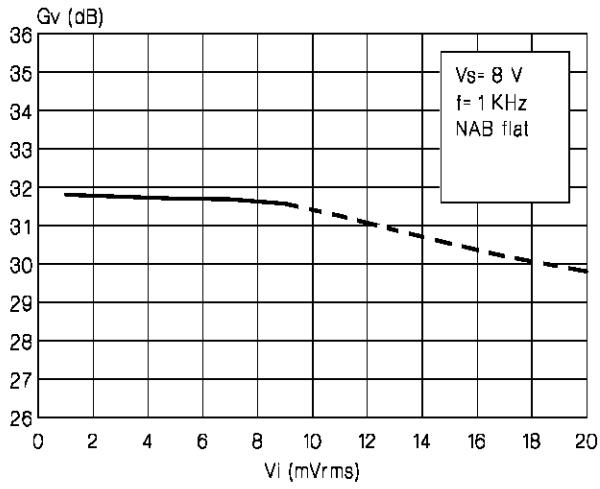
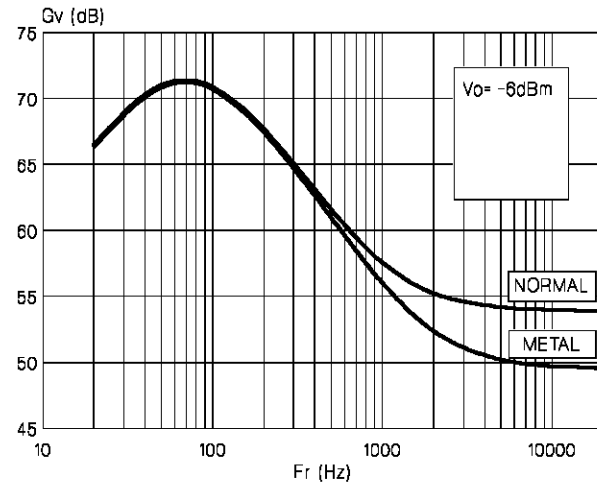


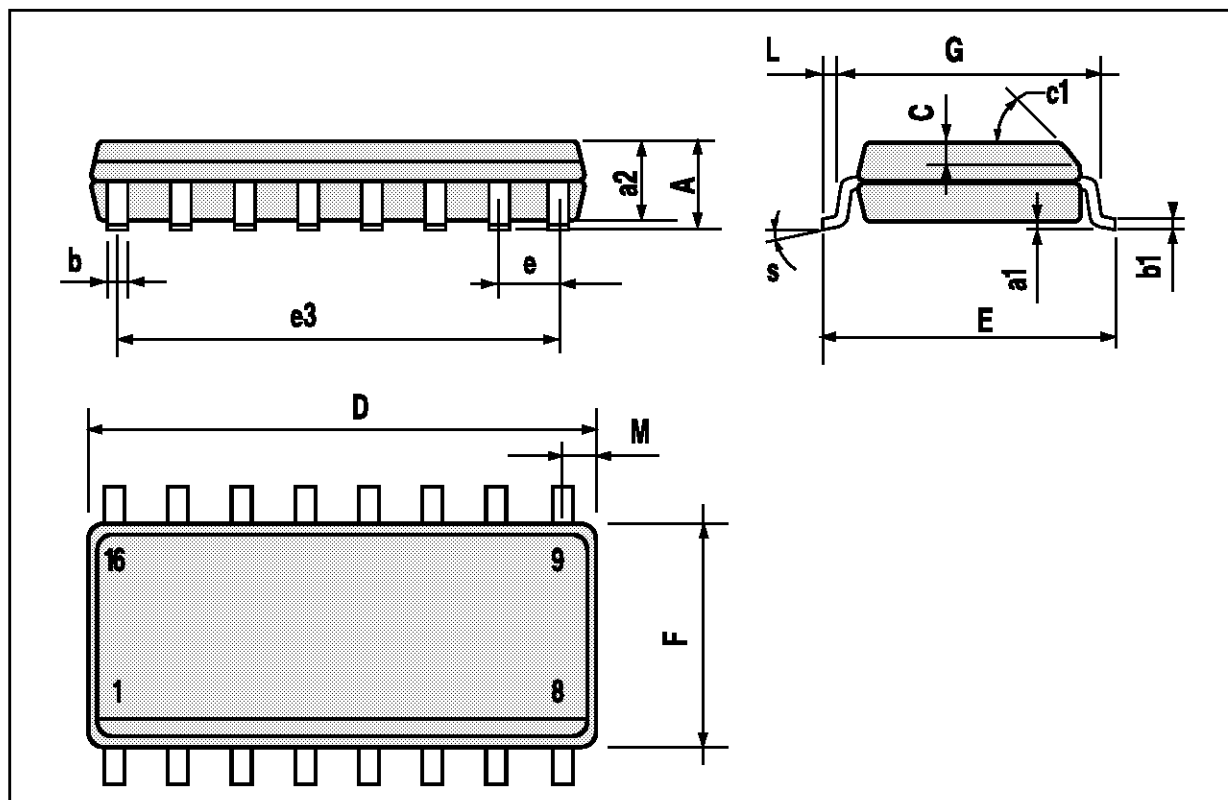
Figure 20: NAB Network





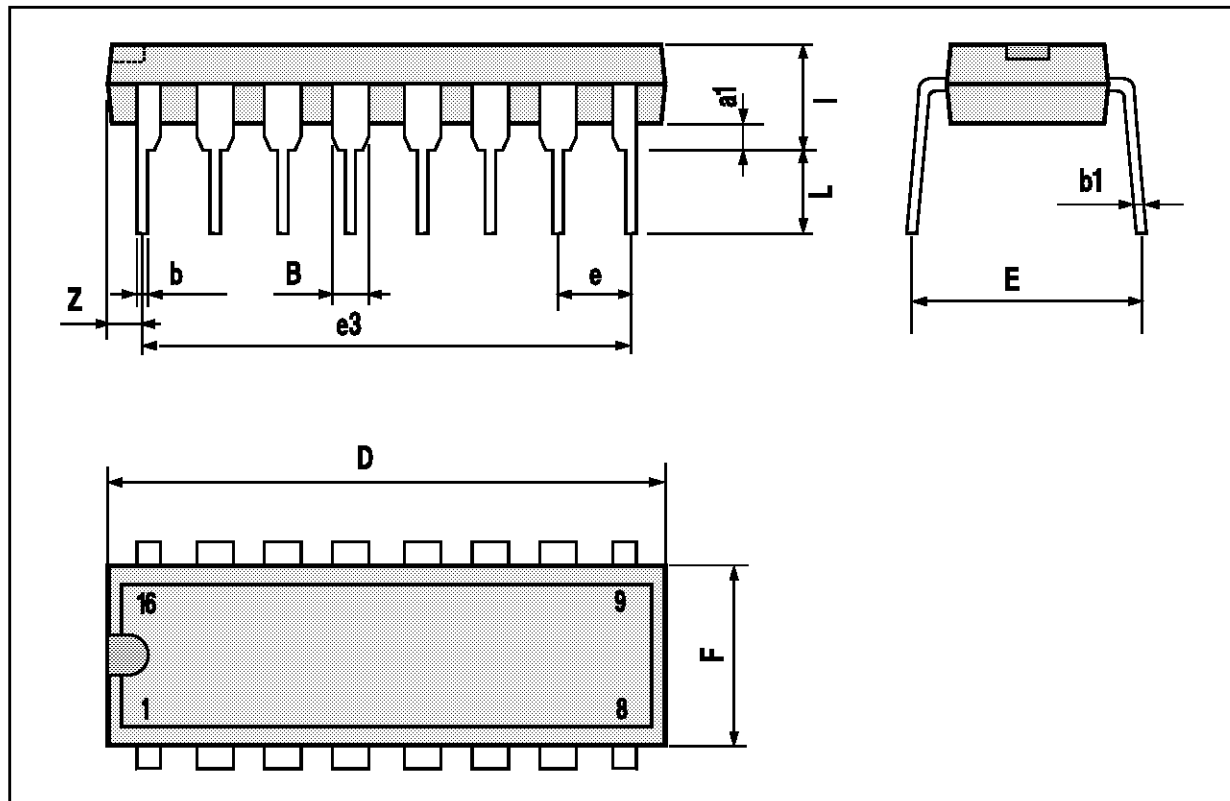
## SO16 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45 (typ.)					
D	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.62			0.024
S	8 (max.)					



DIP16 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



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